



20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

20 V

Current

0.5A

Features

- RDS(ON), VGS@4.5V, ID@0.5A<0.4Ω
- RDS(ON) , VGS@2.5V, ID@0.3A<0.7Ω
- RDS(ON), VGS@1.8V, ID@0.1A<1.2Ω(typ.)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 Std.
- AEC-Q101 qualified

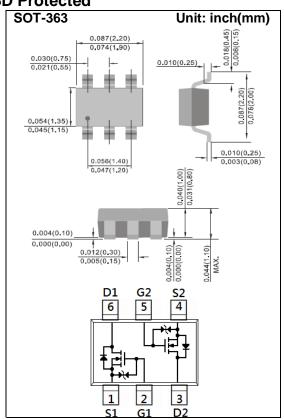
Mechanical Data

• Case: SOT-363 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0002 ounces, 0.006 grams

Marking: T02



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	0.5	Α
Pulsed Drain Current (Note 4)		I _{DM}	2.0	Α
Power Dissipation	T _a =25°C	P_{D}	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ hetaJA}$	357	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_D =250uA	20	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.4	0.63	1.0	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =0.5A	-	0.32	0.4	Ω		
		V _{GS} =2.5V,I _D =0.3A	-	0.6	0.7			
		V _{GS} =1.8V,I _D =0.1A	-	1.2	-			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =16V, V _{GS} =0V	-	0.02	1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 10V, V _{DS} =0V	-	<u>+</u> 2	<u>+</u> 10	uA		
Dynamic (Note 5)								
Total Gate Charge	Q_g	V _{DS} =10V, I _D =0.5A, V _{GS} =4.5V ^(Note 1,2)	-	0.9	-	nC		
Gate-Source Charge	Q_gs		-	0.3	-			
Gate-Drain Charge	Q_gd		-	0.1	-			
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	-	39	-	pF		
Output Capacitance	Coss		-	18	-			
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	9	-			
Turn-On Delay Time	td _(on)	\/ _10\/ I _0.5A	-	3	-			
Turn-On Rise Time	tr	V_{DD} =10V, I_{D} =0.5A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1,2)	-	22	-	ns		
Turn-Off Delay Time	td _(off)		-	7	-			
Turn-Off Fall Time	tf	1\G-022	-	19	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	,			-	0.4	А		
Diode Forward Current	I _S							
Diode Forward Voltage	V_{SD}	I _S =0.5A, V _{GS} =0V	-	0.91	1.3	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

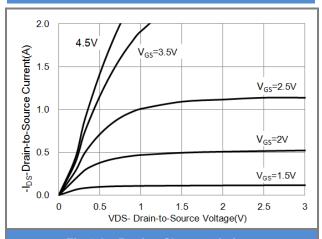


Fig.1 On-Region Characteristics

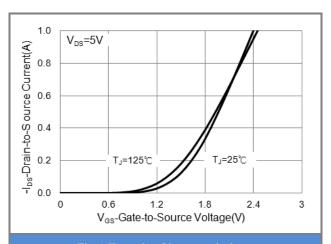


Fig.2 Transfer Characteristics

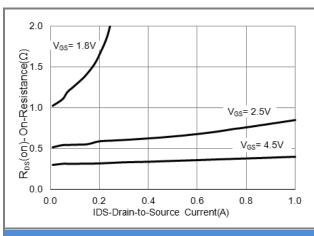


Fig.3 On-Resistance vs. Drain Current

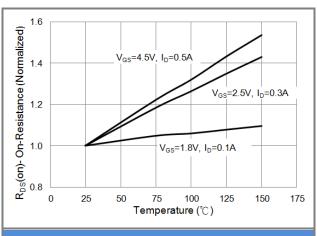


Fig.4 On-Resistance vs. Junction temperature

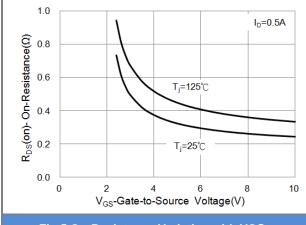


Fig.5 On-Resistance Variation with VGS.

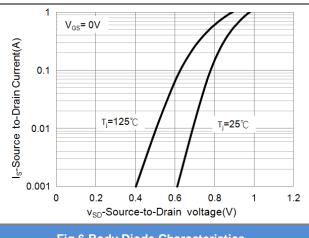


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

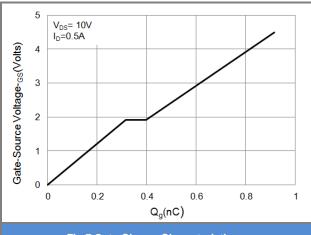


Fig.7 Gate-Charge Characteristics

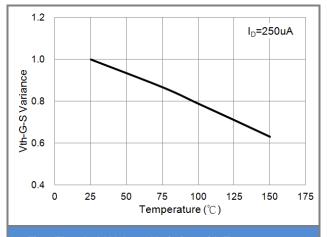


Fig.8 Threshold Voltage Variation with Temperature.

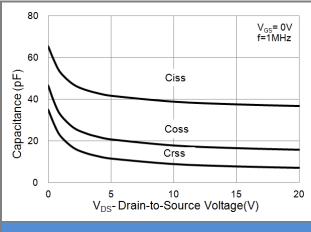


Fig.9 Threshold Voltage Variation with Temperature.

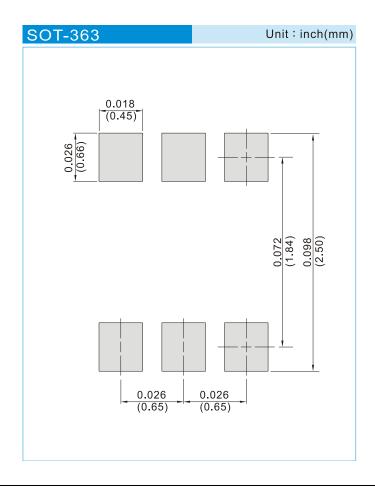




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJT7802-AU_R1_000A1	SOT-363	3K pcs / 7" reel	T02	Halogen free
PJT7802-AU_R2_000A1	SOT-363	10K pcs / 13" reel	T02	Halogen free

MOUNTING PAD LAYOUT







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